

LL052AT523

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LL052AT523

Surface Mount TVS For ESD Protection Diode

Features

- Protects tow data line.
- Low capacitance : 0.25pF Typical (I/O to I/O).
- Low leakage current : $0.1\mu\text{A}$ @ V_{RWM} (typ.).
- Low clamping voltage.
- Provide transient protection:
IEC 61000-4-2 (ESD) $\pm 25\text{KV}$ (Air), $\pm 17\text{KV}$ (Contact).
IEC 61000-4-4 (EFT) 40A (5/50ns).
Cable discharge event (CDE).
- Lead-free parts meet RoHS requirements.
- Suffix "-H" indicates Halogen-free part, ex.LL052AT523-H.

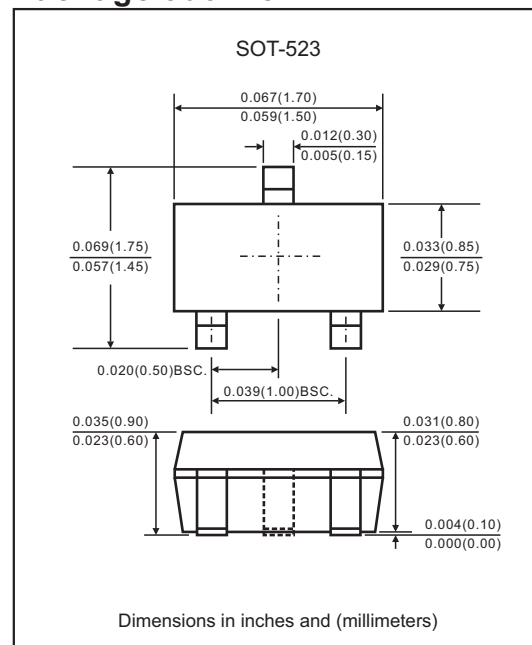
Applications

- Serial ATA.
- PCI Express.
- USB 2.0 Power and data line protection.
- Display ports.

Mechanical data

- Epoxy:UL94-V0 rated flame retardant.
- Case : Molded plastic, SOT-523.
- Terminals : Solder plated, solder able per MIL-STD-750, Method 2026.
- Polarity : Indicated by cathode band.
- Mounting Position : Any.
- Weight : Approximated 0.002 gram.

Package outline



Maximum ratings (At $T_A=25^\circ\text{C}$ unless otherwise noted)

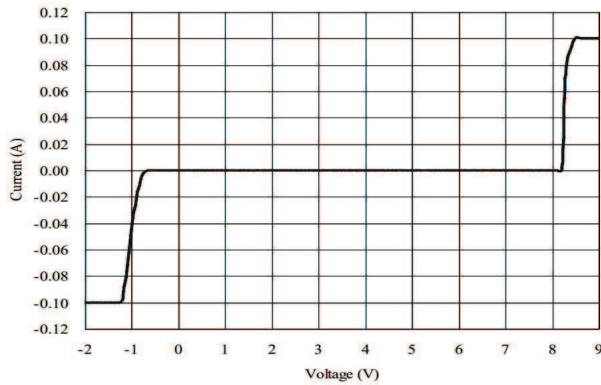
Parameter	Symbol	Value	Unit
Peak pulse power ($t_p=8/20\mu\text{s}$)	P_{PP}	12	W
Electrostatic discharge voltage (IEC61000-4-2 Contact) (IEC61000-4-2 Air)	V_{ESD}	± 17 ± 25	KV
Peak pulse current ($t_p=8/20\mu\text{s}$, IEC61000-4-5)	I_{PP}	1	A
Operating temperature	T_J	+125	$^\circ\text{C}$
Storage temperature	T_{STG}	-55 to +150	$^\circ\text{C}$

Electrical characteristics (At $T_A=25^\circ\text{C}$ unless otherwise noted)

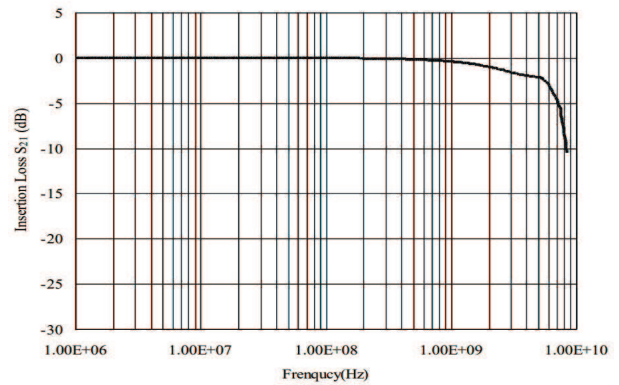
Parameter	Conditions	Symbol	Min.	Typ.	Max.	Unit
Reverse stand-off voltage		V_{RWM}			5	V
Breakdown voltage	$I_T=1\text{mA}$ (Between I/O and GND)	V_{BR}	6.0	8.0	10	V
Reverse leakage current	$V_{\text{RWM}}=5\text{V}$ (Between I/O and GND)	I_{R}		0.1	1.0	μA
Clamping voltage	$I_{\text{PP}}=1\text{A}$, $t_p=8/20\mu\text{s}$ (Between I/O and GND)	V_{C}			12	V
Junction capacitance	$V_{\text{R}}=0\text{V}$, $f=1\text{MHz}$ (Between I/O and GND)	C_j		0.8	1.2	pF
	$V_{\text{R}}=0\text{V}$, $f=1\text{MHz}$ (Between I/O and I/O)			0.25	0.5	

Rating and characteristic curves(LL052AT523)

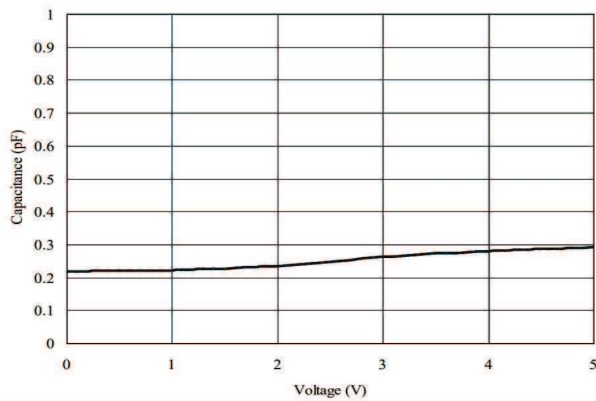
Voltage Sweeping of I/O to I/O



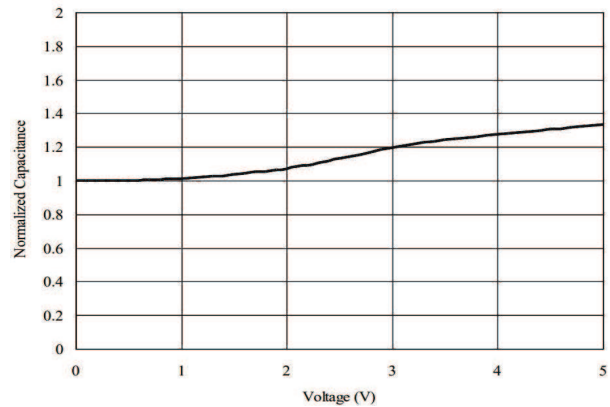
Insertion Loss S₂₁ of I/O to I/O



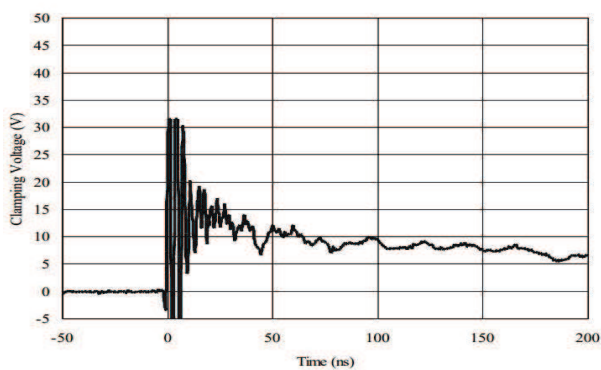
Capacitance vs. Reverse Voltage



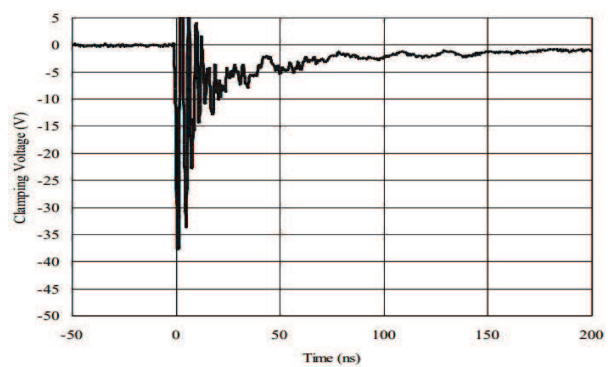
Normalized Capacitance vs. Reverse Voltage



ESD Clamping of I/O to GND (+8kV Contact per IEC 61000-4-2)

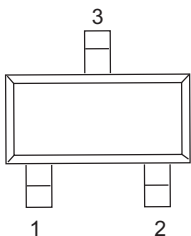
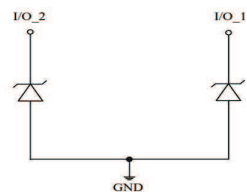


ESD Clamping of I/O to GND (-8kV Contact per IEC 61000-4-2)

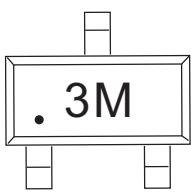


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Pinning information

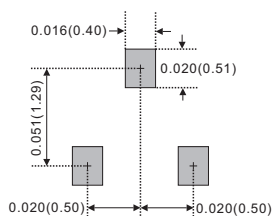
Pin	Simplified outline	Symbol
Pin1 I/O_1 Pin2 I/O_2 Pin3 GND		

Marking

Type number	Marking code
LL052AT523	

Suggested solder pad layout

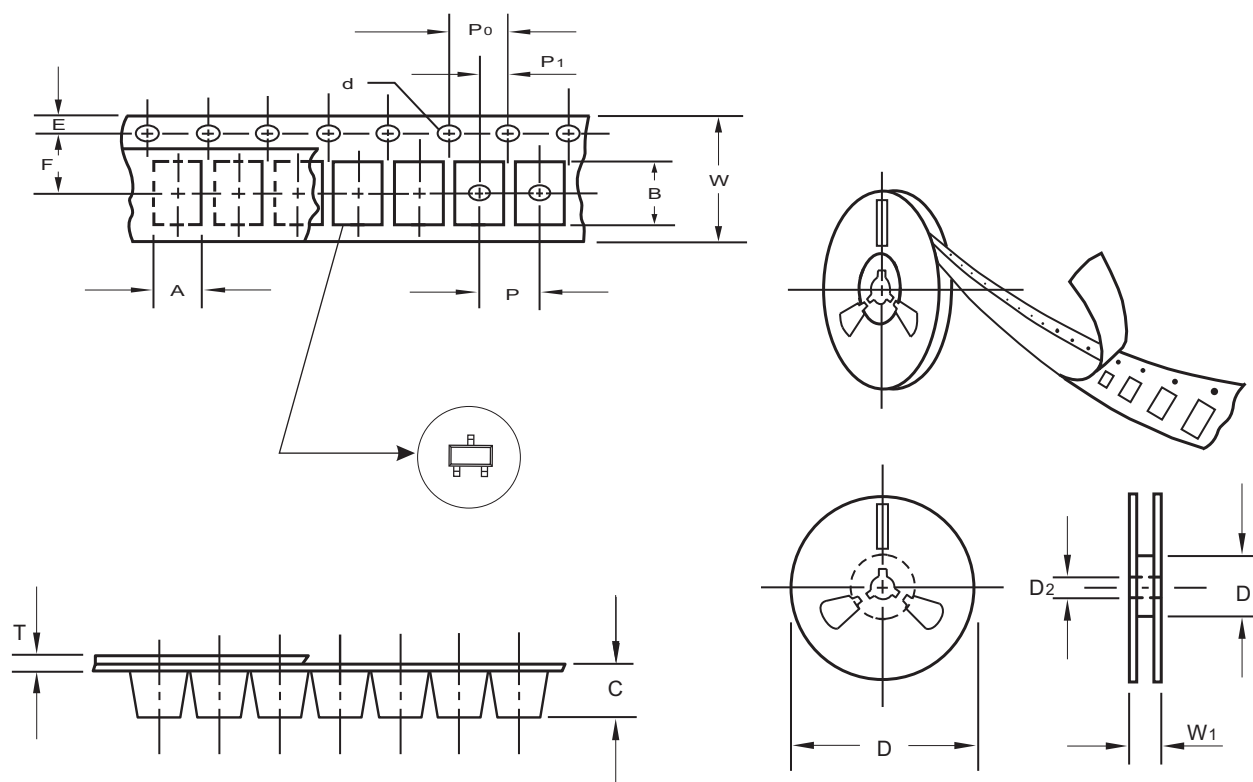
SOT-523



Dimensions in inches and (millimeters)

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Packing information



unit:mm

Item	Symbol	Tolerance	SOT-523
Carrier width	A	0.1	1.85
Carrier length	B	0.1	1.85
Carrier depth	C	0.1	0.875
Sprocket hole	d	0.1	1.5
13" Reel outside diameter	D	2.0	-
13" Reel inner diameter	D1	min	-
7" Reel outside diameter	D	2.0	178.00
7" Reel inner diameter	D1	min	60.00
Feed hole diameter	D2	0.5	13.00
Sprocket hole position	E	0.1	1.75
Punch hole position	F	0.1	3.50
Punch hole pitch	P	0.1	4.00
Sprocket hole pitch	P0	0.1	4.00
Embossment center	P1	0.1	2.00
Overall tape thickness	T	0.1	0.23
Tape width	W	0.3	8.00
Reel width	W1	1.0	9.50

Note: Devices are packed in accordance with EIA standard RS-481-A and specifications listed above.

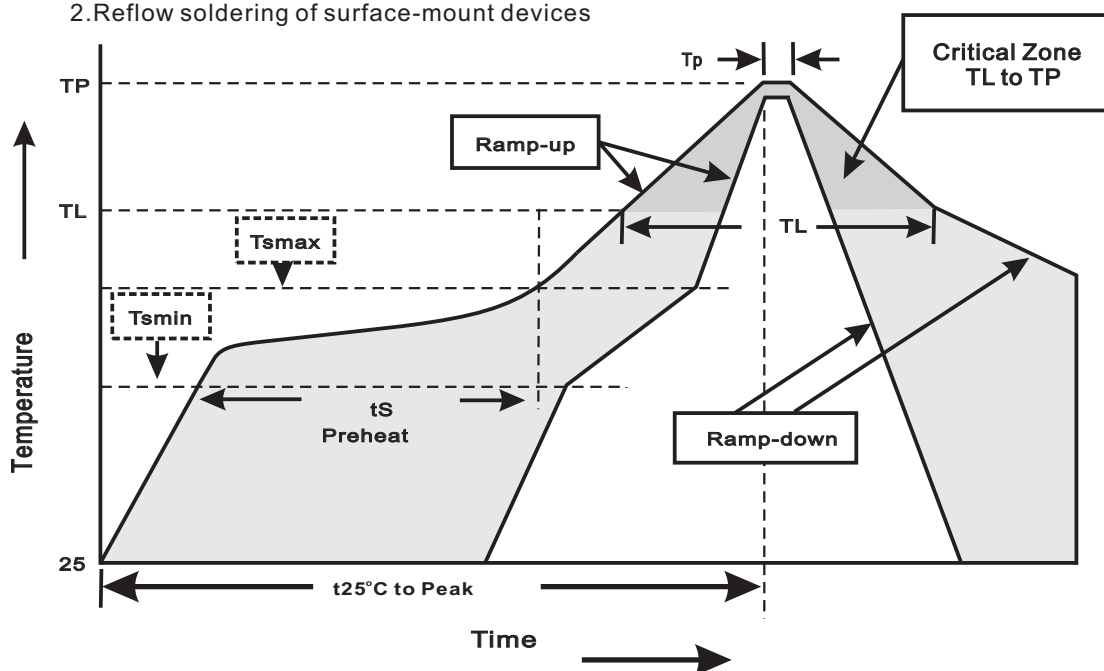
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Reel packing

PACKAGE	REEL SIZE	REEL (pcs)	COMPONENT SPACING (m/m)	BOX (pcs)	INNER BOX (m/m)	REEL DIA, (m/m)	CARTON SIZE (m/m)	CARTON (pcs)	APPROX. GROSS WEIGHT (kg)
SOT-523	7"	3,000	4.0	30,000	183*183*123	178	382*262*387	240,000	9.5

Suggested thermal profiles for soldering processes

- 1.Storage environment: Temperature=5°C~40°C Humidity=55%±25%
- 2.Reflow soldering of surface-mount devices



- 3.Reflow soldering

Profile Feature	Soldering Condition
Average ramp-up rate(TL to TP)	<3°C/sec
Preheat -Temperature Min(Tsmin) -Temperature Max(Tsmax) -Time(min to max)(ts)	150°C 200°C 60~120sec
Tsmax to TL -Ramp-upRate	<3°C/sec
Time maintained above: -Temperature(TL) -Time(tL)	217°C 60~260sec
Peak Temperature(TP)	255°C-0/+5°C
Time within 5°C of actual Peak Temperature(tp)	10~30sec
Ramp-down Rate	<6°C/sec
Time 25°C to Peak Temperature	<6minutes

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High reliability test capabilities

Item Test	Conditions	Reference
1. Solder Resistance	at $260\pm 5^{\circ}\text{C}$ for $10\pm 2\text{sec.}$	MIL-STD-750D METHOD-2031
2. Solderability	at $245\pm 5^{\circ}\text{C}$ for 5 sec.	MIL-STD-202F METHOD-208
3. High Temperature Reverse Bias	$V_{\text{BR}}=V_{\text{BR MIN}}*80\%$ at $T_{\text{J}}=150^{\circ}\text{C}$ for 168 hrs.	MIL-STD-750D METHOD-1038
4. Pressure Cooker	$15P_{\text{SIG}}$ at $T_{\text{A}}=121^{\circ}\text{C}$ for 4 hrs.	JESD22-A102
5. Temperature Cycling	-55°C to $+125^{\circ}\text{C}$ dwelled for 30 min. and transferred for 5min. total 10 cycles.	MIL-STD-750D METHOD-1051
6. Humidity	at $T_{\text{A}}=85^{\circ}\text{C}$, RH=85% for 1000hrs.	MIL-STD-750D METHOD-1021
7. High Temperature Storage Life	at 150°C for 1000 hrs.	MIL-STD-750D METHOD-1031